

# Designer's™ Data Sheet

## SWITCHMODE™

### NPN Bipolar Power Transistor

#### For Switching Power Supply Applications

The BUL147/BUL147F have an applications specific state-of-the-art die designed for use in electric fluorescent lamp ballasts to 180 Watts and in Switchmode Power supplies for all types of electronic equipment. These high-voltage/high-speed transistors offer the following:

- Improved Efficiency Due to Low Base Drive Requirements:
  - High and Flat DC Current Gain
  - Fast Switching
  - No Coil Required in Base Circuit for Turn-Off (No Current Tail)
- Parametric Distributions are Tight and Consistent Lot-to-Lot
- Two Package Choices: Standard TO-220 or Isolated TO-220
- BUL147F, Isolated Case 221D, is UL Recognized to 3500 VRMS: File #E69369

#### MAXIMUM RATINGS

Rating	Symbol	BUL147	BUL147F	Unit
Collector-Emitter Sustaining Voltage	$V_{CEO}$	400		Vdc
Collector-Emitter Breakdown Voltage	$V_{CES}$	700		Vdc
Emitter-Base Voltage	$V_{EBO}$	9.0		Vdc
Collector Current — Continuous	$I_C$	8.0		Adc
— Peak(1)	$I_{CM}$	16		
Base Current — Continuous	$I_B$	4.0		Adc
— Peak(1)	$I_{BM}$	8.0		
RMS Isolated Voltage(2) (for 1 sec, R.H. < 30%, $T_C = 25^\circ\text{C}$ )	Test No. 1 Per Fig. 22a	—	4500	Volts
	Test No. 2 Per Fig. 22b	—	3500	
	Test No. 3 Per Fig. 22c	—	1500	
Total Device Dissipation ( $T_C = 25^\circ\text{C}$ ) Derate above $25^\circ\text{C}$	$P_D$	125	45	Watts
		1.0	0.36	W/ $^\circ\text{C}$
Operating and Storage Temperature	$T_J, T_{stg}$	- 65 to 150		$^\circ\text{C}$

#### THERMAL CHARACTERISTICS

Rating	Symbol	BUL44	BUL44F	Unit
Thermal Resistance — Junction to Case	$R_{\theta JC}$	1.0	2.78	$^\circ\text{C/W}$
— Junction to Ambient	$R_{\theta JA}$	62.5	62.5	
Maximum Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	$T_L$	260		$^\circ\text{C}$

#### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
----------------	--------	-----	-----	-----	------

#### OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage ( $I_C = 100\text{ mA}, L = 25\text{ mH}$ )	$V_{CEO(sus)}$	400	—	—	Vdc
Collector Cutoff Current ( $V_{CE} = \text{Rated } V_{CEO}, I_B = 0$ )	$I_{CEO}$	—	—	100	$\mu\text{Adc}$
Collector Cutoff Current ( $V_{CE} = \text{Rated } V_{CES}, V_{EB} = 0$ ) ( $T_C = 125^\circ\text{C}$ ) ( $V_{CE} = 500\text{ V}, V_{EB} = 0$ ) ( $T_C = 125^\circ\text{C}$ )	$I_{CES}$	—	—	100	$\mu\text{Adc}$
		—	—	500	
		—	—	100	
Emitter Cutoff Current ( $V_{EB} = 9.0\text{ Vdc}, I_C = 0$ )	$I_{EBO}$	—	—	100	$\mu\text{Adc}$

(1) Pulse Test: Pulse Width = 5.0 ms, Duty Cycle  $\leq 10\%$ .

(2) Proper strike and creepage distance must be provided.

(continued)

Designer's and SWITCHMODE are trademarks of Motorola, Inc.

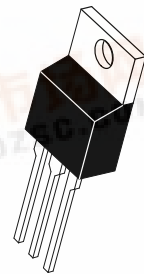
**Designer's Data for "Worst Case" Conditions** — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves representing boundaries on device characteristics — are given to facilitate "worst case" design.

Preferred devices are Motorola recommended choices for future use and best overall value.

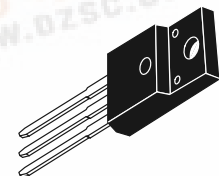
**BUL147\***  
**BUL147F\***

\*Motorola Preferred Device

**POWER TRANSISTOR**  
**8.0 AMPERES**  
**700 VOLTS**  
**45 and 125 WATTS**



**BUL147**  
**CASE 221A-06**  
**TO-220AB**



**BUL147F**  
**CASE 221D-02**  
**ISOLATED TO-220 TYPE**  
**UL RECOGNIZED**



REV 1



**MOTOROLA**

# BUL147 BUL147F

## ELECTRICAL CHARACTERISTICS — continued (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>ON CHARACTERISTICS</b>					
Base–Emitter Saturation Voltage (I <sub>C</sub> = 2.0 Adc, I <sub>B</sub> = 0.2 Adc) (I <sub>C</sub> = 4.5 Adc, I <sub>B</sub> = 0.9 Adc)	V <sub>BE(sat)</sub>	— —	0.82 0.92	1.1 1.25	Vdc
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 2.0 Adc, I <sub>B</sub> = 0.2 Adc)  (I <sub>C</sub> = 4.5 Adc, I <sub>B</sub> = 0.9 Adc)	V <sub>CE(sat)</sub>	— — —	0.25 0.3 0.35	0.5 0.5 0.7	Vdc
				0.8	
DC Current Gain (I <sub>C</sub> = 1.0 Adc, V <sub>CE</sub> = 5.0 Vdc)  (I <sub>C</sub> = 4.5 Adc, V <sub>CE</sub> = 1.0 Vdc)  (I <sub>C</sub> = 2.0 Adc, V <sub>CE</sub> = 1.0 Vdc) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 5.0 Vdc)	h <sub>FE</sub>	14 — 8.0 7.0 10 10	— 30 12 11 18 20	34 — — — — —	—

## DYNAMIC CHARACTERISTICS

Current Gain Bandwidth (I <sub>C</sub> = 0.5 Adc, V <sub>CE</sub> = 10 Vdc, f = 1.0 MHz)	f <sub>T</sub>	—	14	—	MHz	
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>ob</sub>	—	100	175	pF	
Input Capacitance (V <sub>EB</sub> = 8.0 V)	C <sub>ib</sub>	—	1750	2500	pF	
Dynamic Saturation Voltage: Determined 1.0 μs and 3.0 μs respectively after rising I <sub>B1</sub> reaches 90% of final I <sub>B1</sub> (see Figure 18)	(I <sub>C</sub> = 2.0 Adc I <sub>B1</sub> = 200 mAdc V <sub>CC</sub> = 300 V)	1.0 μs (T <sub>C</sub> = 125°C)	—	3.0	—	Volts
		3.0 μs (T <sub>C</sub> = 125°C)	—	5.5	—	
	(I <sub>C</sub> = 5.0 Adc I <sub>B1</sub> = 0.9 Adc V <sub>CC</sub> = 300 V)	1.0 μs (T <sub>C</sub> = 125°C)	—	0.8	—	
		3.0 μs (T <sub>C</sub> = 125°C)	—	1.4	—	

## SWITCHING CHARACTERISTICS: Resistive Load (D.C. ≤ 10%, Pulse Width = 20 μs)

Turn–On Time	(I <sub>C</sub> = 2.0 Adc, I <sub>B1</sub> = 0.2 Adc I <sub>B2</sub> = 1.0 Adc, V <sub>CC</sub> = 300 V)  (T <sub>C</sub> = 125°C)	t <sub>on</sub>	— —	200 190	350 —	ns
Turn–Off Time		t <sub>off</sub>	— —	1.0 1.6	2.5 —	μs
Turn–On Time	(I <sub>C</sub> = 4.5 Adc, I <sub>B1</sub> = 0.9 Adc I <sub>B1</sub> = 2.25 Adc, V <sub>CC</sub> = 300 V)  (T <sub>C</sub> = 125°C)	t <sub>on</sub>	— —	85 100	150 —	ns
Turn–Off Time		t <sub>off</sub>	— —	1.5 2.0	2.5 —	μs

## SWITCHING CHARACTERISTICS: Inductive Load (V<sub>clamp</sub> = 300 V, V<sub>CC</sub> = 15 V, L = 200 μH)

Fall Time	(I <sub>C</sub> = 2.0 Adc, I <sub>B1</sub> = 0.2 Adc I <sub>B2</sub> = 1.0 Adc)  (T <sub>C</sub> = 125°C)	t <sub>fi</sub>	— —	100 120	180 —	ns
Storage Time		t <sub>si</sub>	— —	1.3 1.9	2.5 —	μs
Crossover Time		t <sub>c</sub>	— —	210 230	350 —	ns
Fall Time	(I <sub>C</sub> = 4.5 Adc, I <sub>B1</sub> = 0.9 Adc I <sub>B2</sub> = 2.25 Adc)  (T <sub>C</sub> = 125°C)	t <sub>fi</sub>	— —	80 100	150 —	ns
Storage Time		t <sub>si</sub>	— —	1.6 2.1	3.2 —	μs
Crossover Time		t <sub>c</sub>	— —	170 200	300 —	ns
Fall Time	(I <sub>C</sub> = 4.5 Adc, I <sub>B1</sub> = 0.9 Adc I <sub>B2</sub> = 0.9 Adc)  (T <sub>C</sub> = 125°C)	t <sub>fi</sub>	60 —	— 150	180 —	ns
Storage Time		t <sub>si</sub>	2.6 —	— 4.3	3.8 —	μs
Crossover Time		t <sub>c</sub>	— —	200 330	350 —	ns

TYPICAL STATIC CHARACTERISTICS

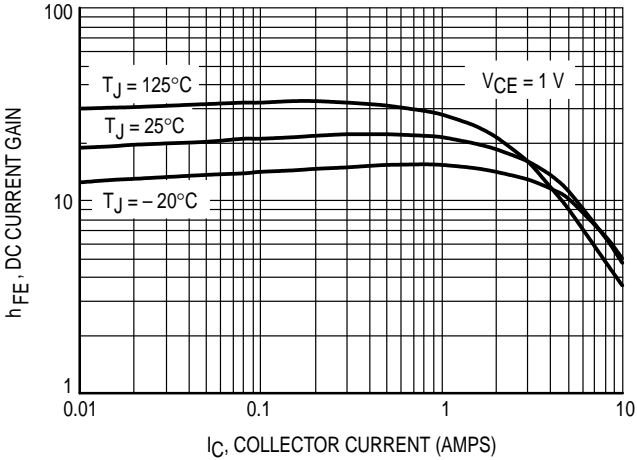


Figure 1. DC Current Gain @ 1 Volt

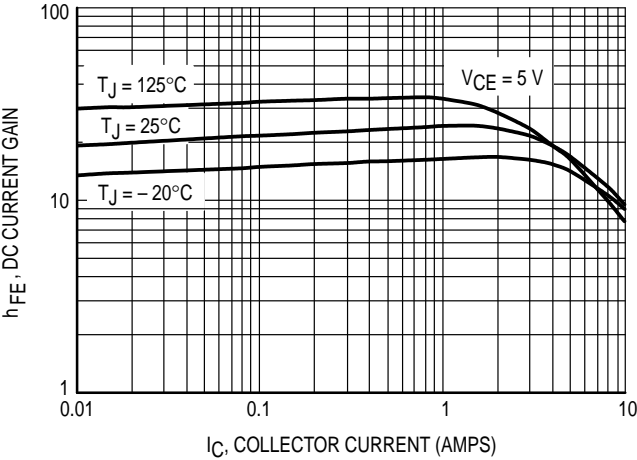


Figure 2. DC Current Gain @ 5 Volts

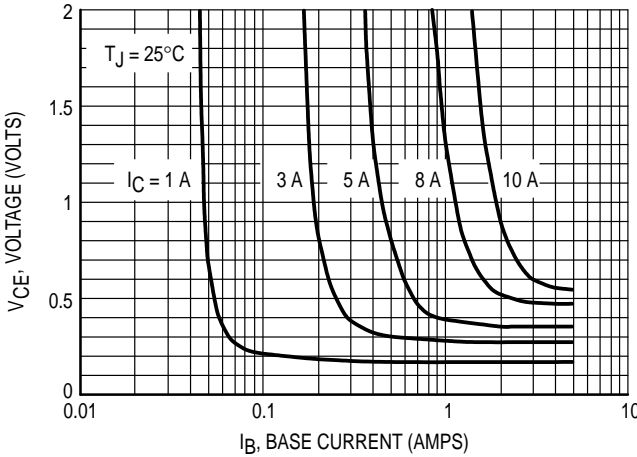


Figure 3. Collector Saturation Region

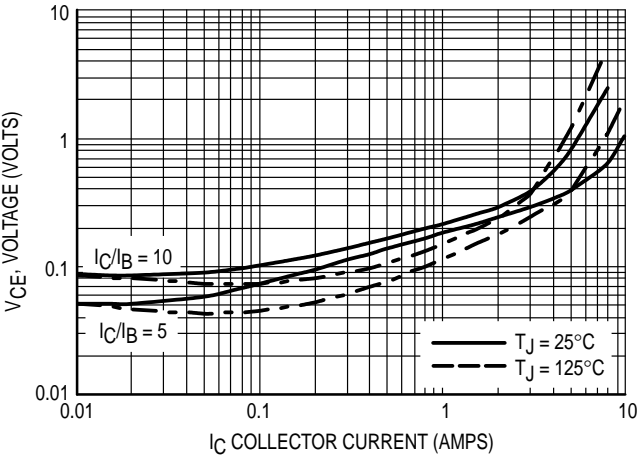


Figure 4. Collector-Emitter Saturation Voltage

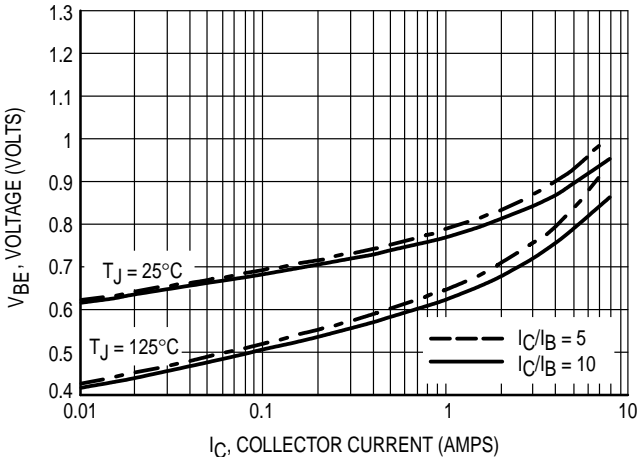


Figure 5. Base-Emitter Saturation Region

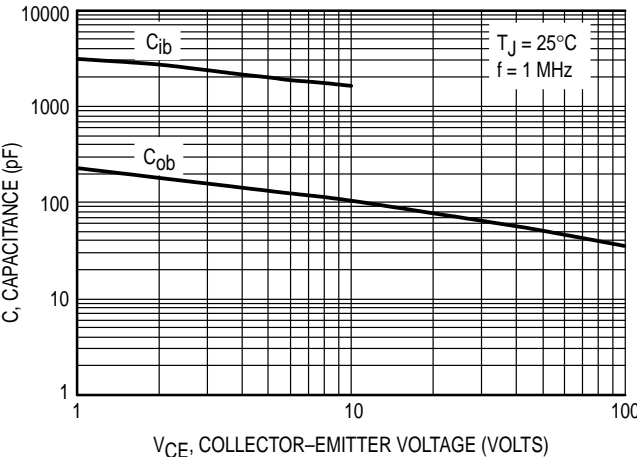
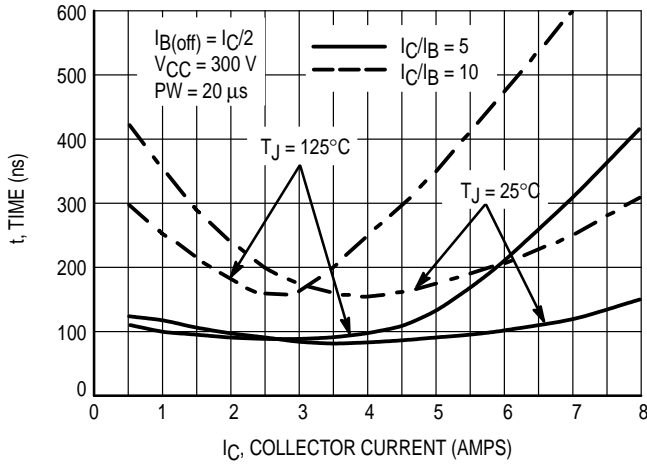
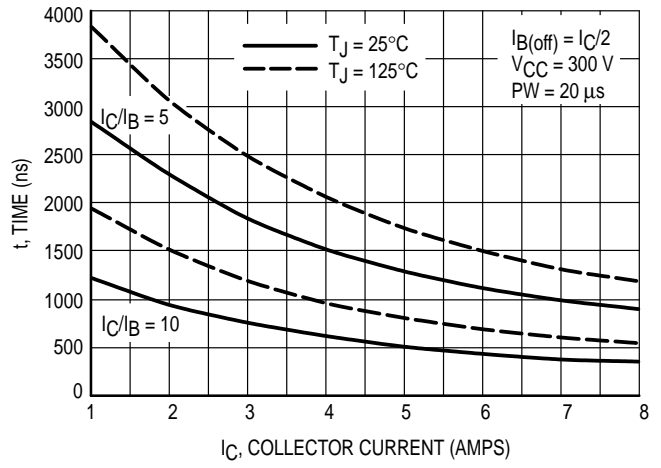


Figure 6. Capacitance

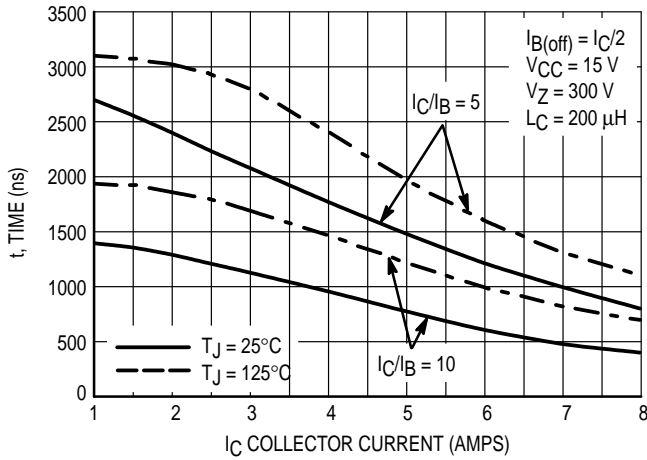
**TYPICAL SWITCHING CHARACTERISTICS**  
( $I_{B2} = I_C/2$  for all switching)



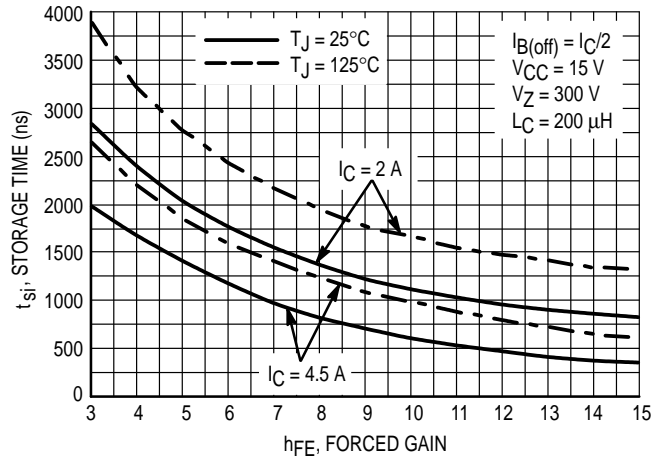
**Figure 7. Resistive Switching,  $t_{on}$**



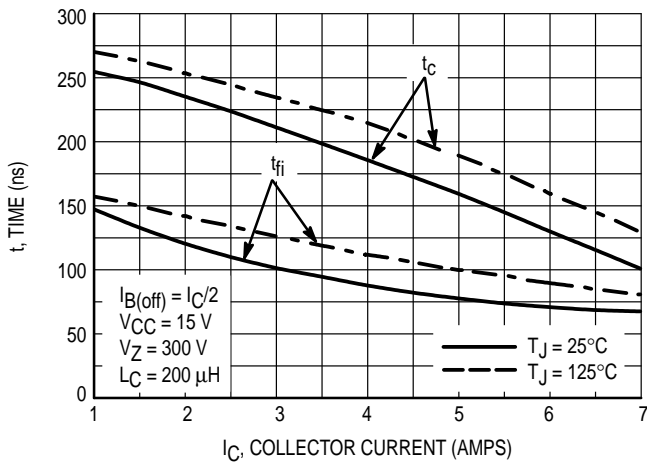
**Figure 8. Resistive Switching,  $t_{off}$**



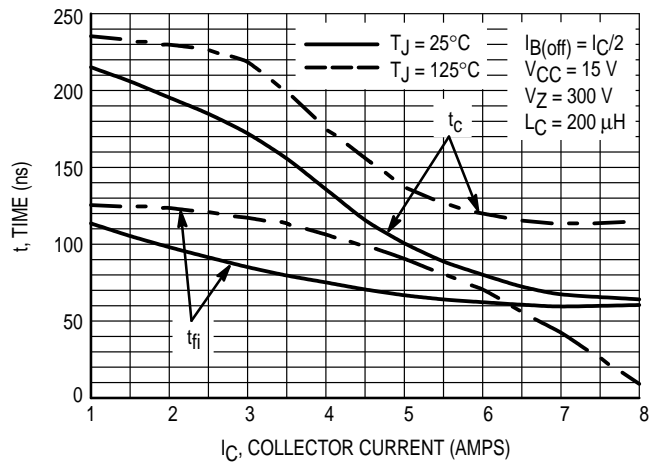
**Figure 9. Inductive Storage Time,  $t_{si}$**



**Figure 10. Inductive Storage Time,  $t_{si}(h_{FE})$**

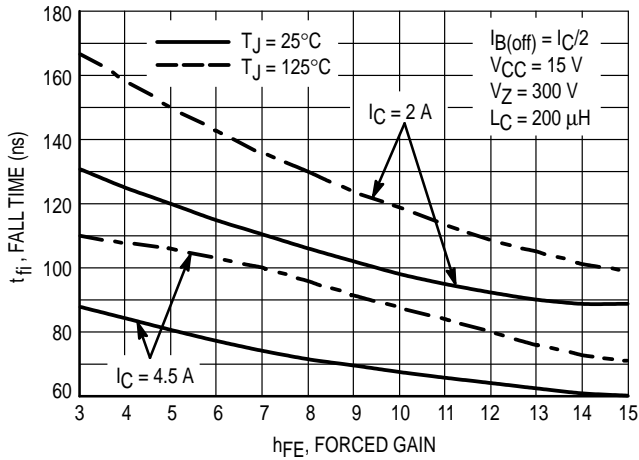


**Figure 11. Inductive Switching,  $t_c$  and  $t_{fi}$**   
 $I_C/I_B = 5$

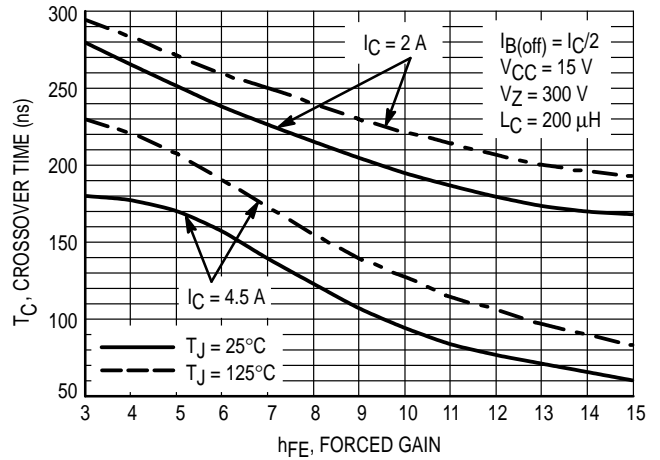


**Figure 12. Inductive Switching,  $t_c$  and  $t_{fi}$**   
 $I_C/I_B = 10$

**TYPICAL SWITCHING CHARACTERISTICS**  
( $I_{B2} = I_C/2$  for all switching)

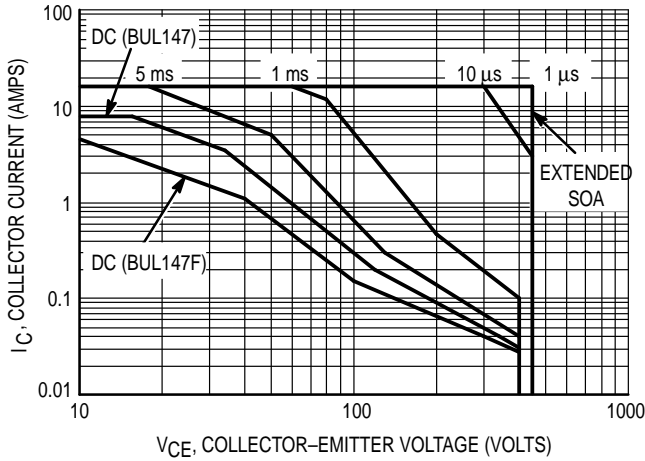


**Figure 13. Inductive Fall Time**

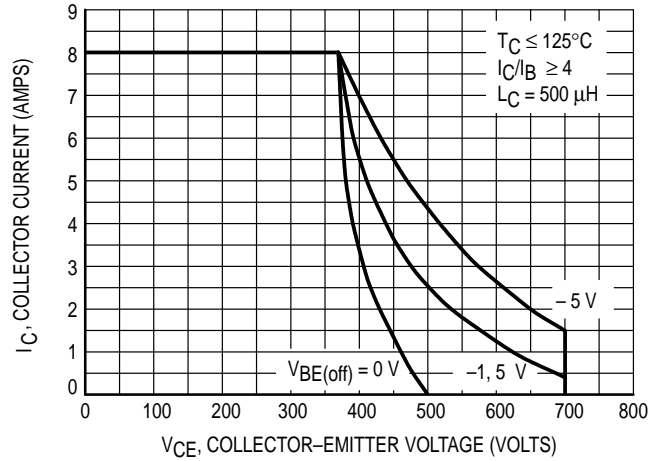


**Figure 14. Inductive Crossover Time**

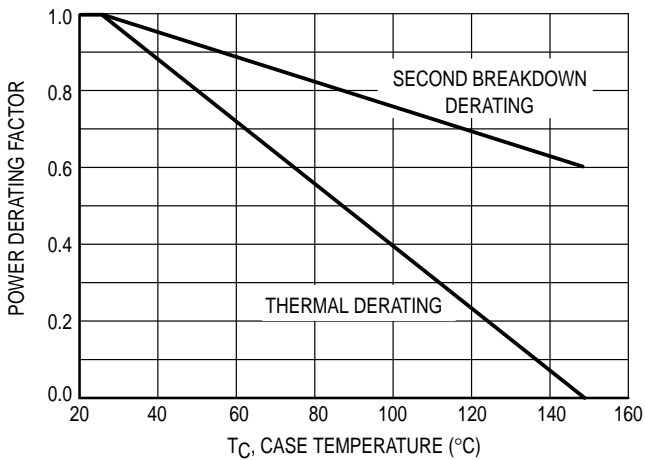
**GUARANTEED SAFE OPERATING AREA INFORMATION**



**Figure 15. Forward Bias Safe Operating Area**



**Figure 16. Reverse Bias Switching Safe Operating Area**



**Figure 17. Forward Bias Power Derating**

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate. The data of Figure 15 is based on  $T_C = 25^\circ\text{C}$ ;  $T_J(\text{pk})$  is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated when  $T_C > 25^\circ\text{C}$ . Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown in Figure 15 may be found at any case temperature by using the appropriate curve on Figure 17.  $T_J(\text{pk})$  may be calculated from the data in Figure 20 and 21. At any case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown. For inductive loads, high voltage and current must be sustained simultaneously during turn-off with the base-to-emitter junction reverse-biased. The safe level is specified as a reverse-biased safe operating area (Figure 16). This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode.



TYPICAL THERMAL RESPONSE

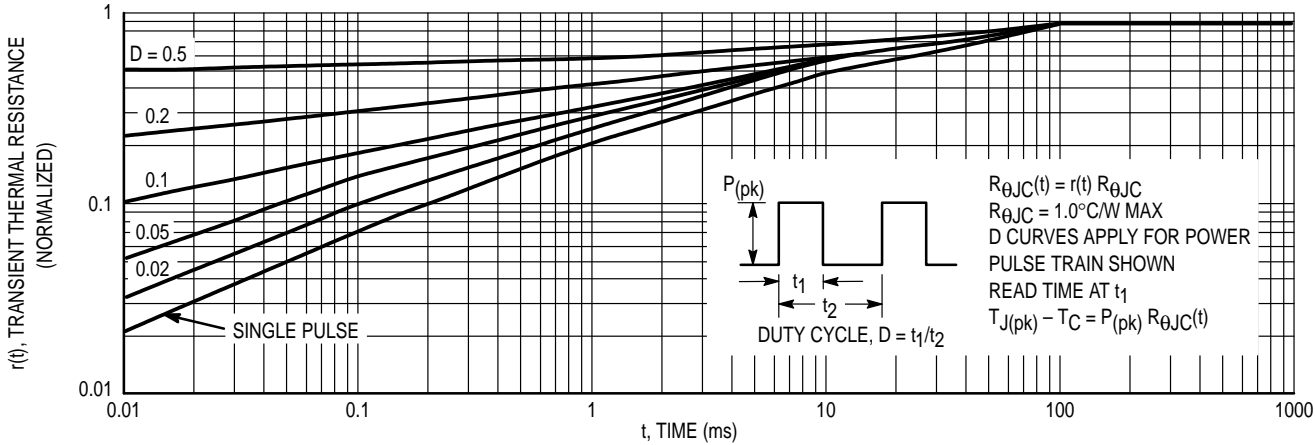


Figure 20. Typical Thermal Response ( $Z_{\theta JC}(t)$ ) for BUL147

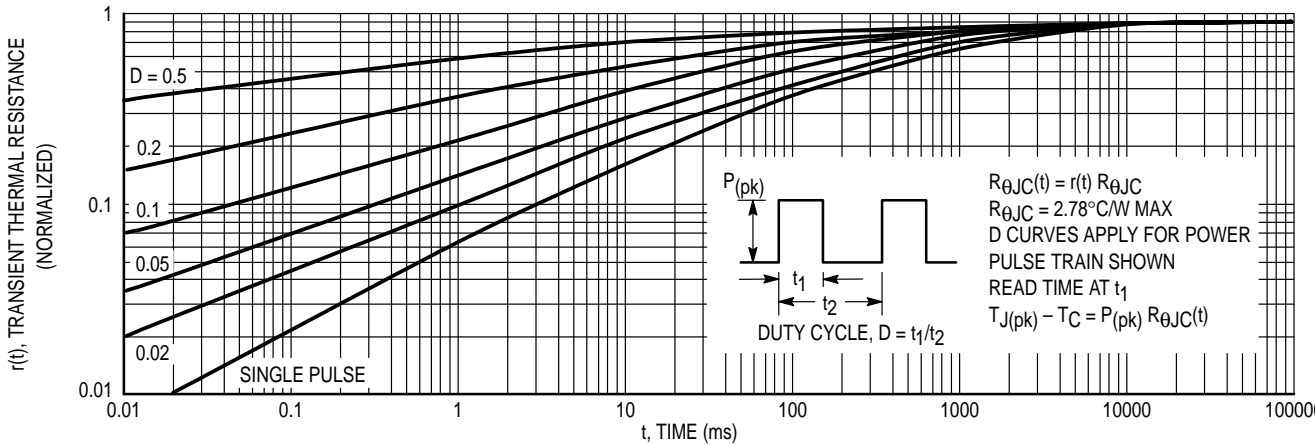
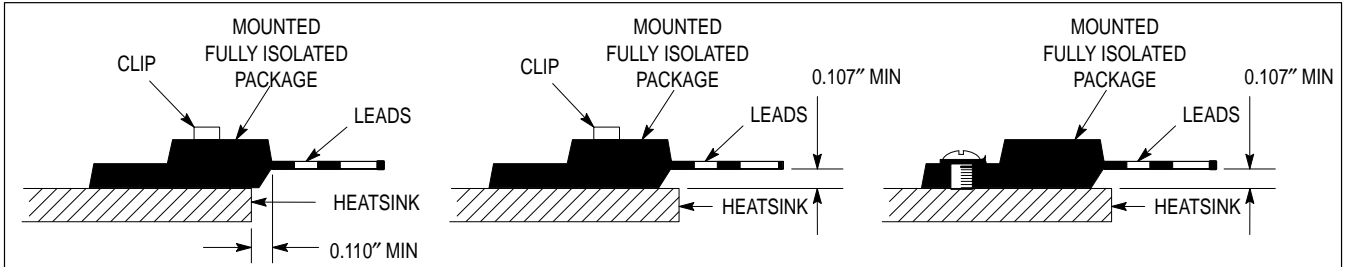


Figure 21. Typical Thermal Response ( $Z_{\theta JC}(t)$ ) for BUL147F

**TEST CONDITIONS FOR ISOLATION TESTS\***



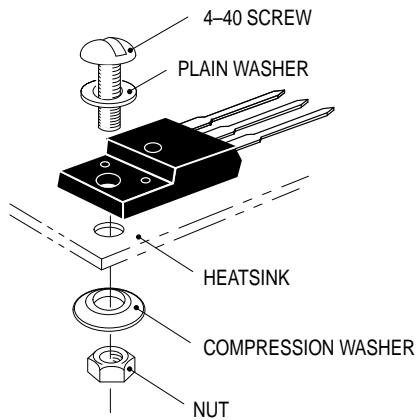
**Figure 22a. Screw or Clip Mounting Position for Isolation Test Number 1**

**Figure 22b. Clip Mounting Position for Isolation Test Number 2**

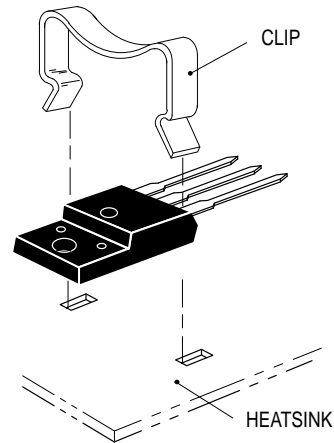
**Figure 22c. Screw Mounting Position for Isolation Test Number 3**

\* Measurement made between leads and heatsink with all leads shorted together.

**MOUNTING INFORMATION\*\***



**Figure 23a. Screw-Mounted**



**Figure 23b. Clip-Mounted**

**Figure 23. Typical Mounting Techniques for Isolated Package**

Laboratory tests on a limited number of samples indicate, when using the screw and compression washer mounting technique, a screw torque of 6 to 8 in · lbs is sufficient to provide maximum power dissipation capability. The compression washer helps to maintain a constant pressure on the package over time and during large temperature excursions.

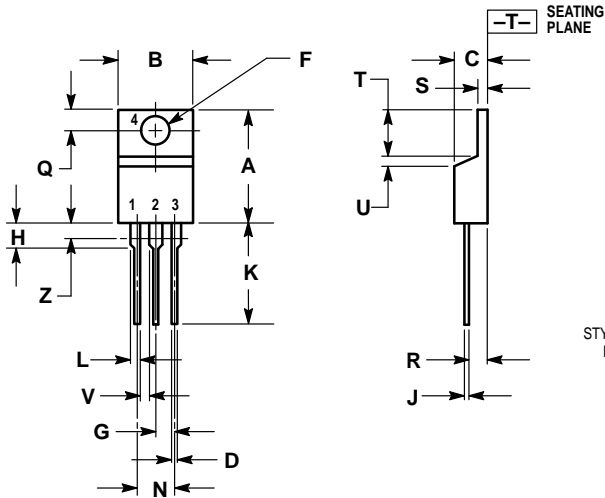
Destructive laboratory tests show that using a hex head 4-40 screw, without washers, and applying a torque in excess of 20 in · lbs will cause the plastic to crack around the mounting hole, resulting in a loss of isolation capability.

Additional tests on slotted 4-40 screws indicate that the screw slot fails between 15 to 20 in · lbs without adversely affecting the package. However, in order to positively ensure the package integrity of the fully isolated device, Motorola does not recommend exceeding 10 in · lbs of mounting torque under any mounting conditions.

\*\* For more information about mounting power semiconductors see Application Note AN1040.



**PACKAGE DIMENSIONS**

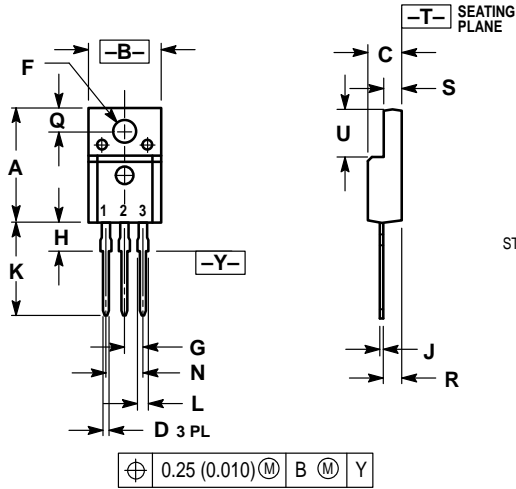


- NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: INCH.  
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	—	1.15	—
Z	—	0.080	—	2.04

- STYLE 1:  
 PIN 1. BASE  
 2. COLLECTOR  
 3. EMITTER  
 4. COLLECTOR

**BUL44  
 CASE 221A-06  
 TO-220AB  
 ISSUE Y**



- NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: INCH.


DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.621	0.629	15.78	15.97
B	0.394	0.402	10.01	10.21
C	0.181	0.189	4.60	4.80
D	0.026	0.034	0.67	0.86
F	0.121	0.129	3.08	3.27
G	0.100 BSC	—	2.54 BSC	—
H	0.123	0.129	3.13	3.27
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
N	0.200 BSC	—	5.08 BSC	—
Q	0.126	0.134	3.21	3.40
R	0.107	0.111	2.72	2.81
S	0.096	0.104	2.44	2.64
U	0.259	0.267	6.58	6.78

- STYLE 2:  
 PIN 1. BASE  
 2. COLLECTOR  
 3. EMITTER

⊕ 0.25 (0.010) M B M Y

**BUL44F  
 CASE 221D-02  
 (ISOLATED TO-220 TYPE)  
 ISSUE D**

## BUL147 BUL147F

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters can and do vary in different applications. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and  are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

### How to reach us:

**USA / EUROPE:** Motorola Literature Distribution;  
P.O. Box 20912; Phoenix, Arizona 85036. 1-800-441-2447

**MFAX:** RMFAX0@email.sps.mot.com – TOUCHTONE (602) 244-6609  
**INTERNET:** <http://Design-NET.com>

**JAPAN:** Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki,  
6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-3521-8315

**HONG KONG:** Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,  
51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298

